TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

T A 8 2 6 5 K

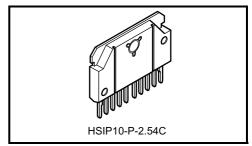
Dual Audio Power Amplifier

TA8265K is a high-output audio power IC developed for outputting audio signals for TV and compact stereos. Fewer external components and a sealed compact 10-pin package means the IC needs only a small space on the printed circuit hoard

The IC incorporates thermal shutdown and load short-protection circuits.

Features

- High output power: Pout = 6 W/channel (Typ.) $(V_{CC} = 20 \text{ V}, \text{RL} = 8 \Omega, \text{f} = 1 \text{ kHz}, \text{THD} = 10\%)$
- Low noise: $V_{no} = 0.14 \text{ mVrms}$ (Typ.) $(V_{CC} = 20 \text{ V}, \text{RL} = 8 \Omega, \text{GV} = 34 \text{dB}, \text{Rg} = 10 \text{ k}\Omega, \text{BW} = 20 \text{ Hz} \sim 20 \text{ kHz})$
- Very few external parts
- Built in thermal shut down protector circuit
- Operating supply voltage range: V_{CC} (opr) = 10~30 V (Ta = 25°C)





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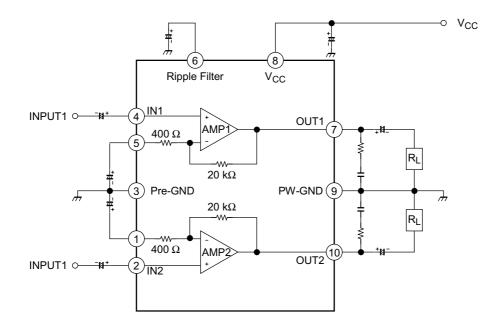
This product generates heat during normal operation. However, substandard performance or malfunction may cause the product and its peripherals to reach abnormally high temperatures. The product is often the final stage (the external output stage) of a circuit. Substandard performance or malfunction of the

destination device to which the circuit supplies output may cause damage to the circuit or to the product. The products described in this document are subject to the foreign exchange and foreign trade laws.

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Block Diagram



Application Information

Voltage gain

The closed loop voltage gain is determined by R_1 , R_2 .

$$G_{V} = 20 \log \frac{R_1 + R_2}{R_2} (dB)$$
$$= 20 \log \frac{20 \log 400 \Omega}{400 \Omega}$$
$$\approx 34 (dB)$$

(a) Amplifier with gain GV <34 (dB)

$$\begin{split} G_V &= 20 \log \frac{R_1 + R_2 + R_4}{R_2 + R_4} (dB) \\ When & R_4 = 220 \ \Omega \\ G_V &\simeq 30 \ (dB) \\ \text{is gein.} \end{split}$$

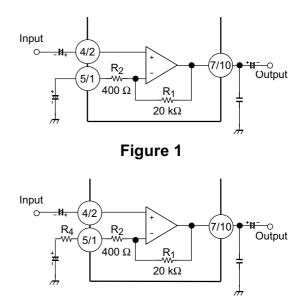
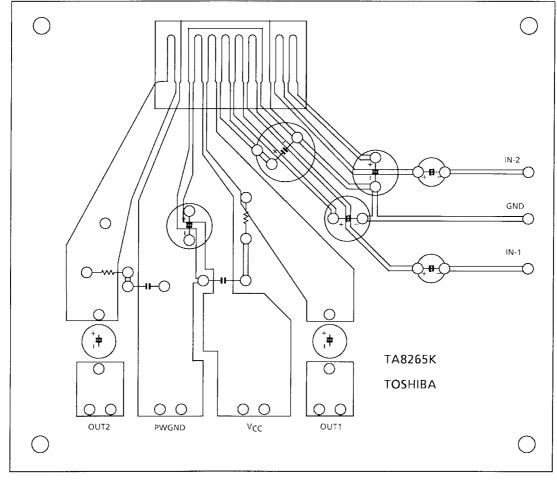


Figure 2

Cautions

This IC is not proof enough against a strong E-M field by CRT which may cause malfunction such as leak. Please set the IC keeping the distance from CRT.

Standard P.C.B



(Bottom view)

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Supply voltage	V _{CC}	30	V	
Output current (peak/ch)	I _{O (peak)}	2	А	
Power dissipation	P _D (Note)	20	W	
Operating temperature	T _{opr}	-20~75	°C	
Storage temperature	T _{stg}	-55~150	°C	

Note: Derated above $Ta = 25^{\circ}C$ in the proportion of 267 mW/°C.

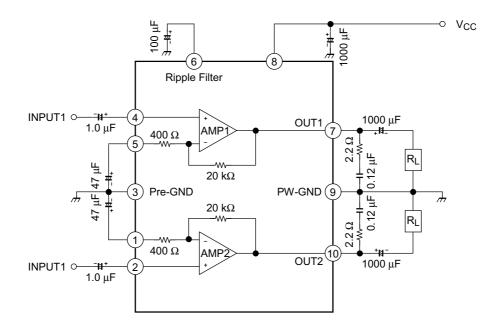
Electrical Characteristics (Unless otherwise specified, V_{CC} = 20 V, R_L = 8 Ω , R_g = 600 Ω , f = 1 kHz, Ta = 25°C)

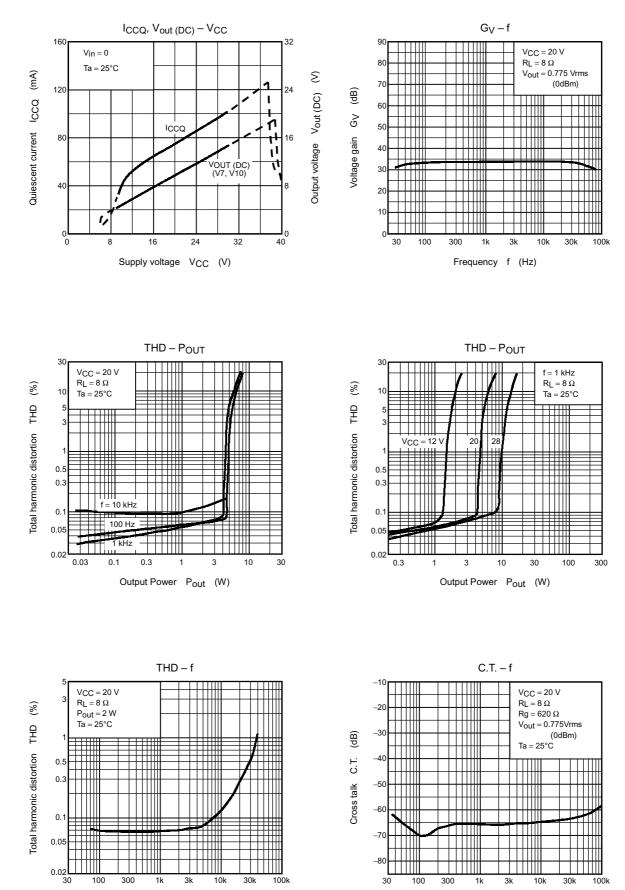
Characteristic	Symbol	Test Circuit Test Condition		Min.	Тур.	Max	Unit
Quiescent current	Iccq	_	$V_{in} = 0$	_	75	130	mA
Output power	P _{out} (1)	_	— THD = 10%		6.0	_	w
	P _{out} (2)	_	THD = 1%	_	4.5	_	vv
Total harmonic distortion	THD	_	P _{out} = 2 W	_	0.1	0.6	%
Closed loop voltage gain	G _V	_	— V _{out} = 0.775 Vrms (0dBm)		34.0	35.5	dB
Cross talk	C.T.	_	V _{out} = 0.775 Vrms (0dBm)	_	-65	_	dB
Input resistance	R _{IN}	_	—	_	30	_	kΩ
Ripple rejection ratio	R.R.	_	$\begin{array}{l} \text{Rg} = 10 \text{ k}\Omega, \text{ f}_{ripple} = 100 \text{ Hz} \\ \text{V}_{ripple} = 0.775 \text{ V}_{rms} \text{ (0dBm)} \end{array}$	-45	-57	_	dB
Output noise voltage	V _{no}	_	Rg = 10 kΩ, BW = 20 Hz~20 kHz	_	0.14	0.3	mVrms

Typ. DC Voltage of Each Terminal ($V_{CC} = 20 V$, Ta = 25°C)

Terminal No.	1	2	3	4	5	6	7	8	9	10
DC voltage (V)	2.1	2.25	GND	2.25	2.1	6.8	9.8	V _{CC}	GND	9.8

Test Circuit

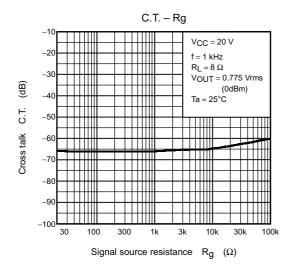


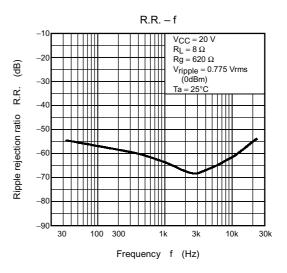


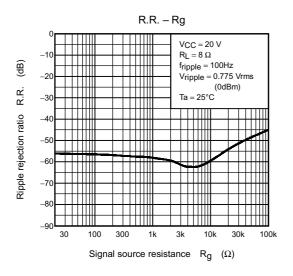
Frequency f (Hz)

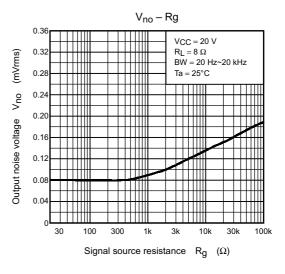
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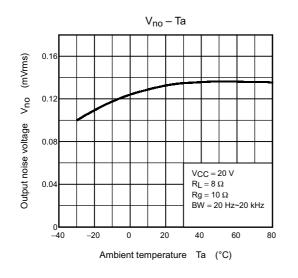
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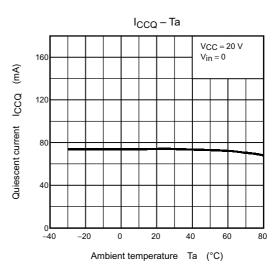


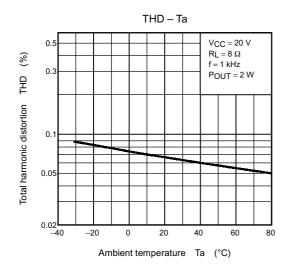


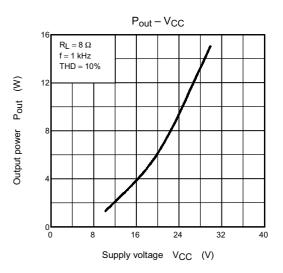


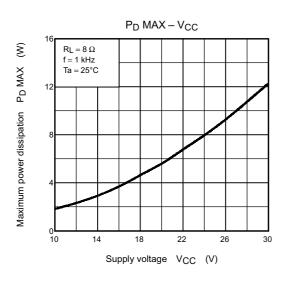


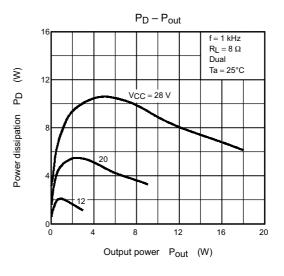


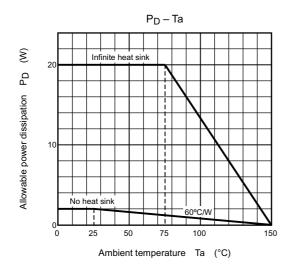




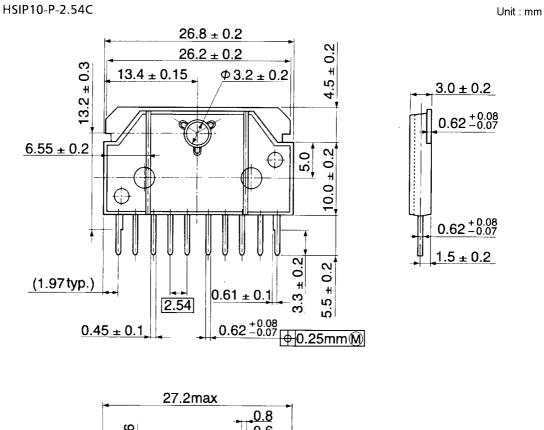


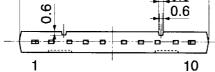






Package Dimensions





Weight: 3.15 g (Typ.)